



# 1 Megabit (128K x 8) UV EPROM and OTP EPROM

#### **DATA BRIEFING**

- FAST ACCESS TIME: 45ns
- LOW POWER "CMOS" CONSUMPTION:
  - Active Current 30mA
  - Standby Current 100μA
- PROGRAMMING VOLTAGE: 12.75V
- ELECTRONIC SIGNATURE for AUTOMATED PROGRAMMING
- PROGRAMMING TIMES of AROUND 12sec. (PRESTO II ALGORITHM)

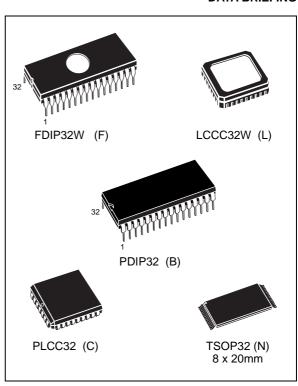


The M27C1001 is a high speed 1 Megabit UV erasable and electrically programmable EPROM ideally suited for microprocessor systems requiring large programs. It is organized as 131,072 by 8 bits.

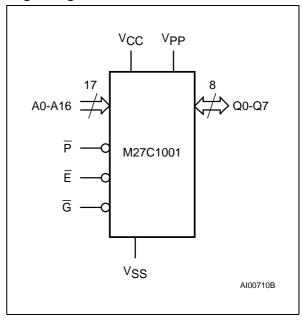
The Window Ceramic Frit-Seal Dual-in-Line and Leadless Chip Carrier packages have transparent lids which allow the user to expose the chip to ultraviolet light to erase the bit pattern. A new pattern can then be written to the device by following the programming procedure. For applications where the content is programmed only one time and erasure is not required, the M27C1001 is offered in both Plastic Dual-in-Line, Plastic Leaded Chip Carrier and Plastic Thin Small Outline packages.

## Signal Names

A0 - A16	Address Inputs
Q0 - Q7	Data Outputs
Ē	Chip Enable
G	Output Enable
P	Program
V <sub>PP</sub>	Program Supply
Vcc	Supply Voltage
Vss	Ground

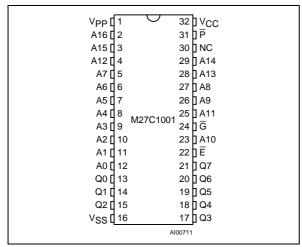


## **Logic Diagram**



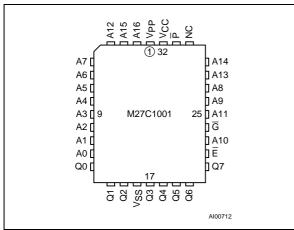
B27C1001/606 1/2

#### **DIP Pin Connections**



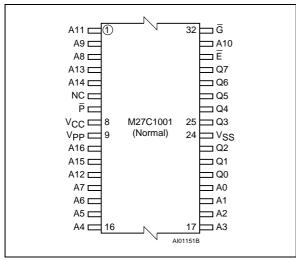
Warning: NC = Not Connected.

## **LCC Pin Connections**



Warning: NC = Not Connected.

## **TSOP Pin Connections**

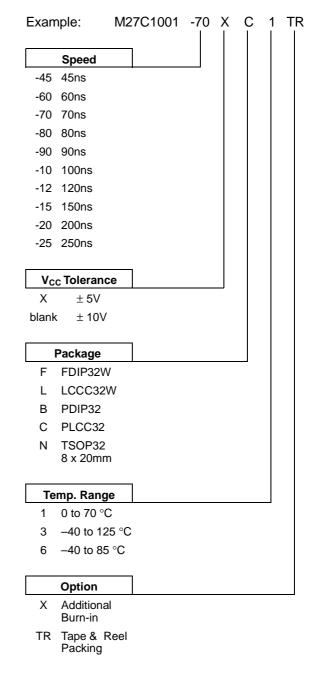


Warning: NC = Not Connected.

## **Ordering Information Scheme**

For a list of available options refer to the current Memory Shortform catalogue.

For further information on any aspect of this device, please contact the SGS-THOMSON Sales Office nearest to you.



Ŋ

warning: NC = Not Conne